

Octal 3-State Transceiver MM74HCT245

Description

The MM74HCT245 3-STATE bi-directional buffer utilizes advanced silicon-gate CMOS technology and is intended for two-way asynchronous communication between data buses. It has high drive current outputs which enable high speed operation even when driving large bus capacitances. This circuit possesses the low power consumption of CMOS circuitry, yet has speeds comparable to low power Schottky TTL circuits.

This device is TTL input compatible and can drive up to 15 LS-TTL loads, and all inputs are protected from damage due to static discharge by diodes to $V_{\rm CC}$ and ground.

The MM74HCT245 has one active low enable input (G), and a direction control (DIR). When the DIR input is HIGH, data flows from the A inputs to the B outputs. When DIR is LOW, data flows from B to A.

MM74HCT devices are intended to interface between TTL and NMOS components and standard CMOS devices. These parts are also plug–in replacements for LS–TTL devices and can be used to reduce power consumption in existing designs.

Features

- TTL Input Compatible
- 3-STATE Outputs for connection to system busses
- High Output Drive Current: 6 mA (min)
- High Speed: 16 ns Typical propagation delay
- Low Power: 160 µA (74HCT Series)

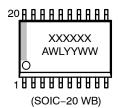


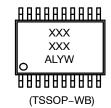




SOIC-20 WB CASE 751D-05 TSSOP-20 WB CASE 948E TSSOP-20 WB CASE 948AQ

MARKING DIAGRAMS



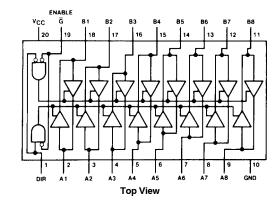


XXXXXX= Specific Device Code

A = Assembly Location

WL = Wafer Lot YY = Year WW = Work Week

CONNECTION DIAGRAM



TRUTH TABLE

Control		Operation
Inputs		
G	DIR	245
L	L	B data to A bus
L	L	A data to B bus
Н	Н	isolation

H = HIGH Level

L = LOW Level

X = Irrelevant

ORDERING INFORMATION

See detailed ordering and shipping information on page 5 of this data sheet.

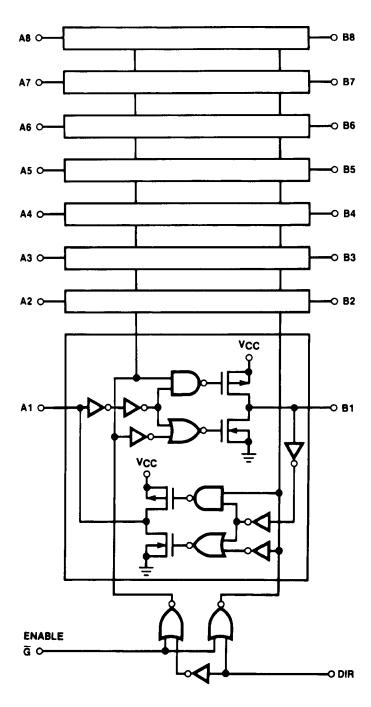


Figure 1. Logic Diagram

ABSOLUTE MAXIMUM RATINGS (Note 1) (Note 2)

Symbol	Parameter	Rating	Unit
V _{CC}	Supply Voltage	-0.5 to +6.5	V
V _{IN}	DC Input Voltage	–0.5 to V _{CC} +0.5	V
V _{OUT}	DC Output Voltage	–0.5 to V _{CC} +0.5	V
I _{IK} , I _{OK}	Clamp Diode Current	±20	mA
lout	DC Output Current, per pin	±35	mA
I _{CC}	Maximum Junction Temperature	±70	mA
T _{STG}	Storage Temperature Range	−65 to +150	°C
P _D	Power Dissipation SOIC TSSOP	1302 833	mW
TL	Lead Temperature (Soldering 10 seconds)	260	°C

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

- 1. Absolute Maximum Ratings are those values beyond which damage to the device may occur.
- 2. Unless otherwise specified all voltages are referenced to ground.

RECOMMENDED OPERATING RANGES

Symbol	Parameter	Min.	Max.	Unit
V _{CC}	Supply Voltage	4.5	5.5	V
V _{IN,} V _{OUT}	DC Input or Output Voltage	0	V _{CC}	V
T _A	Operating Temperature Range	-55	+125	°C
t _r , t _f	Input Rise or Fall Times	-	500	ns

Functional operation above the stresses listed in the Recommended Operating Ranges is not implied. Extended exposure to stresses beyond the Recommended Operating Ranges limits may affect device reliability.

DC ELECTRICAL CHARACTERISTICS (V $_{CC}$ = 5 V $\pm 10\%$, unless otherwise specified.)

			T _A =	- 25°C	T _A = -40°C to 85°C	T _A = -55°C to 125°C	
Symbol	Parameter	Test Conditions	Тур.		Guaranteed Li	mits	Unit
V _{IH}	Minimum HIGH Level Input Voltage	-	-	2.0	2.0	2.0	V
V _{IL}	Maximum LOW Level Input Voltage	-	-	0.8	0.8	0.8	V
V _{OH}	Minimum HIGH Level Output Voltage	$\begin{split} &V_{IN} = V_{IH} \text{ or } V_{IL}, \\ & I_{OUT} = 20 \mu\text{A} \\ & I_{OUT} = 6.0 \text{ mA}, V_{CC} = 4.5 \text{ V} \\ & I_{OUT} = 7.2 \text{ mA}, V_{CC} = 5.5 \text{ V} \end{split}$	V _{CC} 4.2 5.2	V _{CC} ^{-0.1} 3.98 4.98	V _{CC} ^{- 0.1} 3.84 4.84	V _{CC} ^{- 0.1} 3.7 4.7	V
V _{OL}	Maximum LOW Level Output Voltage	$\begin{split} &V_{IN} = V_{IH} \text{ or } V_{IL}, \\ & I_{OUT} = 20 \ \mu\text{A} \\ & I_{OUT} = 6.0 \ \text{mA}, V_{CC} = 4.5 \ \text{V} \\ & I_{OUT} = 7.2 \ \text{mA}, V_{CC} = 5.5 \ \text{V} \end{split}$	0 0.2 0.2	0.1 0.26 0.26	0.1 0.33 0.33	0.1 0.4 0.4	٧
I _{IN}	Maximum Input Current	$V_{IN} = V_{CC}$ or GND V_{IH} or V_{IL} , Pin 1or 19	-	±0.1	±1.0	±1.0	μΑ
I _{OZ}	Maximum 3-STATE Output Leakage Current	$V_{out} = V_{CC}$ or GND $\overline{G} = V_{IH}$	-	±0.5	±5.0	±10	μΑ
I _{CC}	Maximum Quiescent Supply Current	$V_{IN} = V_{CC}$ or GND, $I_{OUT} = 0 \mu A$	-	8	80	160	μΑ
		V _{IN} = 2.4 V or 0.5 V (Note 4)	0.6	1.0	1.3	1.5	mA

^{3.} Measured per input. All other inputs at V_{CC} or ground.

$\textbf{AC ELECTRICAL CHARACTERISTICS} \ (V_{CC} = 5.0 \ V, \ t_f = t_f = 6 \ ns, \ T_A = 25^{\circ}C \ unless \ otherwise \ specified)$

Symbol	Parameter	Test Conditions	Тур.	Guaranteed Limit	Unit
t _{PHL} , t _{PLH}	Maximum Output Propagation Delay	C _L = 45 pF	16	20	ns
t _{PZL} , t _{PZH}	Maximum Output Enable Time	$C_L = 45 \text{ pF}$ $R_L = 1 \text{ kQ}$	29	40	ns
t _{PLZ} , t _{PHZ}	Maximum Output Disable Time	$C_L = 5 pF$ $R_L = 1 kQ$	20	25	ns

AC ELECTRICAL CHARACTERISTICS (V_{CC} = 5.0 V $\pm 10\%$, t_{r} = t_{f} = 6 ns, unless otherwise specified)

			T _A =	25°C	T _A = -40°C to 85°C	T _A = -55°C to 125°C	
Symbol	Parameter	Test Conditions	Тур.		Guaranteed L	imits	Unit
t _{PHL} , t _{PLH}	Maximum Output Propagation De-	C _L = 50 pF	17	23	29	34	ns
	lay	C _L = 150 pF	24	30	38	45	
t _{PZL}	Maximum Output Enable Time	R _L = 1 kQ C _L = 50 pF	31	42	53	63	ns
t _{PZH}	Maximum Output Enable Time	R _L = 1 kQ C _L = 50 pF	23	33	41	49	ns
t _{PHZ} , t _{PLZ}	Maximum Output Disable Time	R _L = 1 kQ C _L = 50 pF	21	30	38	45	ns
t _{THL} , t _{TLH}	Maximum Output Rise and Fall Time	C _L = 50 pF	8	12	15	18	ns
C _{IN}	Maximum Input Capacitance	-	10	15	15	15	pF
C _{OUT}	Maximum Output/Input Capacitance	-	20	25	25	25	pF
C _{PD}	Power Dissipation Capacitance	G = V _{CC} (Note 5) G = GND	7 100	_	-	-	pF pF

^{4.} C_{PD} determines the no load dynamic power consumption, P_D = C_{PD} V_{CC}² f + I_{CC} V_{CC}, and the no load dynamic current consumption, I_S = C_{PD} V_{CC} f + I_{CC}.

ORDERING INFORMATION

Product Number	Marking	Package	Shipping [†]
MM74HCT245MTC	HCT 245A	TSSOP-20 WB,Case, 948E (Pb-Free)	75 Units / Tube
MM74HCT245MTCX	HCT 245A	TSSOP-20 WB, 948AQ (Pb-Free)	2500 Units / Tape and Reel
MM74HCT245WM	HCT245A	SOIC-20 WB (Pb-Free)	38 Units / Tube
MM74HCT245WMX	HCT245A	SOIC-20 WB (Pb-Free)	1000 Units / Tape and Reel

[†]For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, <u>BRD8011/D</u>.

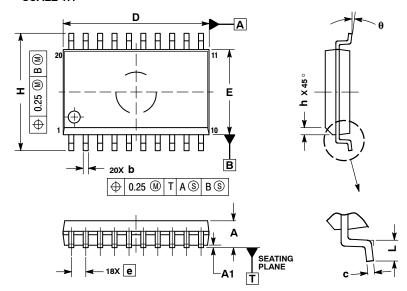




SOIC-20 WB CASE 751D-05 **ISSUE H**

DATE 22 APR 2015

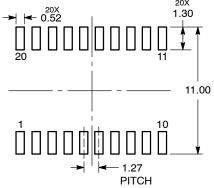
SCALE 1:1



- DIMENSIONS ARE IN MILLIMETERS.
 INTERPRET DIMENSIONS AND TOLERANCES.
- PER ASME Y14.5M, 1994.
 3. DIMENSIONS D AND E DO NOT INCLUDE MOLD
- PROTRUSION.
 MAXIMUM MOLD PROTRUSION 0.15 PER SIDE.
- DIMENSION B DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE PROTRUSION SHALL BE 0.13 TOTAL IN EXCESS OF B DIMENSION AT MAXIMUM MATERIAL

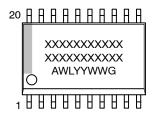
	MILLIMETERS				
DIM	MIN	MAX			
Α	2.35	2.65			
A1	0.10	0.25			
b	0.35	0.49			
С	0.23	0.32			
D	12.65	12.95			
E	7.40	7.60			
е	1.27	BSC			
Н	10.05	10.55			
h	0.25	0.75			
L	0.50	0.90			
A	0 °	7 °			

RECOMMENDED SOLDERING FOOTPRINT*



DIMENSIONS: MILLIMETERS

GENERIC MARKING DIAGRAM*



XXXXX = Specific Device Code = Assembly Location

WL = Wafer Lot ΥY = Year WW = Work Week = Pb-Free Package

*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "•", may or may not be present. Some products may not follow the Generic Marking.

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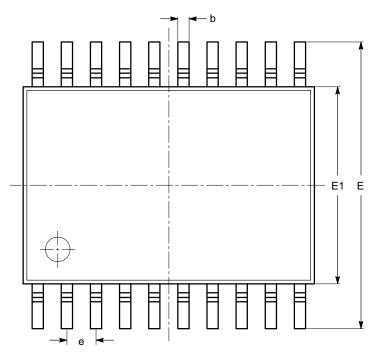
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^{*}For additional information on our Pb-Free strategy and soldering details, please download the onsemi Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.



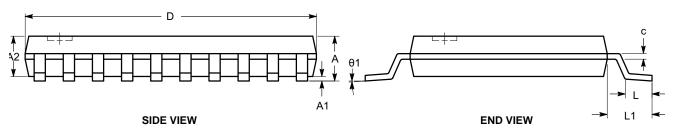
TSSOP20, 4.4x6.5 CASE 948AQ ISSUE A

DATE 19 MAR 2009



SYMBOL	MIN	NOM	MAX
А			1.20
A1	0.05		0.15
A2	0.80		1.05
b	0.19		0.30
С	0.09		0.20
D	6.40	6.50	6.60
Е	6.30	6.40	6.50
E1	4.30	4.40	4.50
е		0.65 BSC	
L	0.45	0.60	0.75
L1		1.00 REF	
θ	0°		8°

TOP VIEW



Notes:

- (1) All dimensions are in millimeters. Angles in degrees.
- (2) Complies with JEDEC MO-153.

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